

RoHS

COMPLIANT HALOGEN

FREE

N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)			
30	0.093 at V _{GS} = 10 V	1.3 ^a	5.41			
50	0.129 at V _{GS} = 4.5 V	1.2	5.41			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_g and UIS Tested
- Compliant to RoHS Directive 2002/95/EC •

Lot Traceability and Date Code

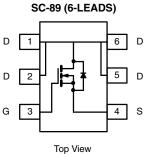
APPLICATIONS

Marking Code xx≿

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Load Switch for Portable Devices

Part # Code



Ordering Information: Si1072X-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V _{DS}	30	V			
Gate-Source Voltage	V _{GS}	± 20				
Continuous Drain Current /T 150 °C)8	T _A = 25 °C	1-	1.3 ^{b, c}			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	- I _D	1.03 ^{b, c}			
Pulsed Drain Current		I _{DM}	6	A		
Avalanche Current	L = 0.1 mH	I _{AS}	8			
Repetitive Avalanche Energy	L = 0.1 IIIA	E _{AS}	3.2	mJ		
Continuous Source-Drain Diode Current	T _A = 25 °C	۱ _S	0.2 ^{b, c}	A		
Manimum Damar Diasinatiana	T _A = 25 °C	- P _D	0.236 ^{b, c}	w		
Maximum Power Dissipation ^a	T _A = 70 °C		0.151 ^{b, c}			
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{b, d}	$t \le 5 s$	В	440	530	°C/W	
Maximum Junction-to-Ambient	Steady State	R _{thJA}	540	650	0/11	

Notes:

a. Based on T_C = 25 °C.

b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 650 °C/W.

Si1072X

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•	·				
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$	30			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		30.4		m\//º(
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	$I_{\rm D} = 250 \mu \text{A}$		- 1.86		mV/°C
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1		3	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zana Cata Malta na Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 85 ^{\circ}\text{C}$			10	
On-State Drain Current ^a	I _{D(on)}	V_{DS} = \geq 5 V, V_{GS} = 10 V	6			А
Dursin Couvers On State Desistance ²	_	V _{GS} = 10 V, I _D = 1.3 A		0.077	0.093	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 1.2 A		0.107	0.129	Ω
Forward Transconductance	9 _{fs}	V _{DS} = 15 V, I _D = 1.3 A		15		mS
Dynamic ^b						
Input Capacitance	C _{iss}			280		
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		55		pF
Reverse Transfer Capacitance	C _{rss}			35		
Total Gate Charge	0	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 1.3 \text{ A}$		5.5	8.3	
	Qg			2.7	4.1	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15$ V, $V_{GS} = 4.5$ V, $I_{D} = 1.3$ A		1.1		
Gate-Drain Charge	Q _{gd}			0.8		
Gate Resistance	Rg	f = 1 MHz		3.5	4.6	Ω
Turn-On Delay Time	t _{d(on)}			7	11	
Rise Time	t _r	V_{DD} = 15 V, R_L = 13.6 Ω		12	18	1
Turn-Off DelayTime	t _{d(off)}	$I_D \cong$ 1.1 A, V_{GEN} = 10 V, R_g = 1 Ω		12	18	
Fall Time	t _f			6	9	20
Turn-On Delay Time	t _{d(on)}			13	20	ns
Rise Time	t _r	V_{DD} = 15 V, R_L = 15.5 Ω		31	47]
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 0.97$ A, V_{GEN} = 10 V, R_g = 1 Ω		9	14	
Fall Time	t _f			6	9	
Drain-Source Body Diode Characteristic	s					
Pulse Diode Forward Current ^a	I _{SM}				6	А
Body Diode Voltage	V _{SD}	I _S = 0.7 A		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			11.2	17	nC
Body Diode Reverse Recovery Charge Q _{rr}				4.5	6.8	
Reverse Recovery Fall Time	ta	I _F = 1.2 A, dl/dt = 100 A/μs		7.5		ns
Reverse Recovery Rise Time	t _b	1		3.7		

Notes:

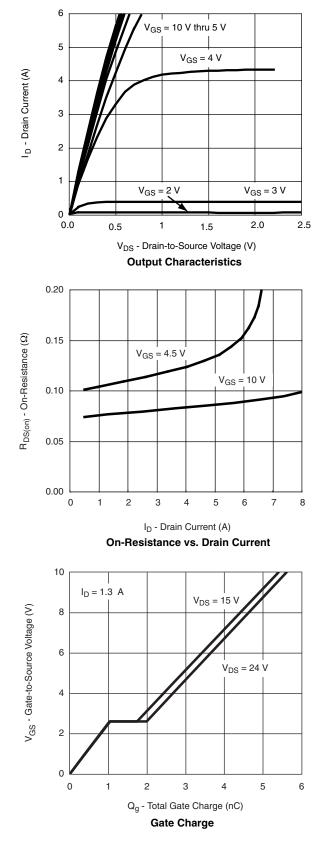
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

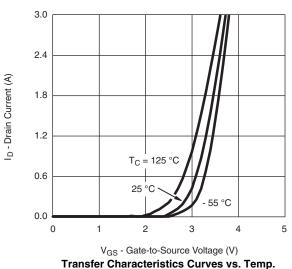
b. Guaranteed by design, not subject to production testing.

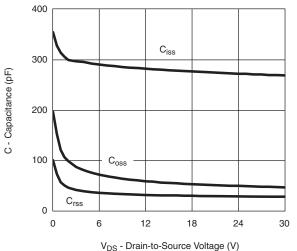
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



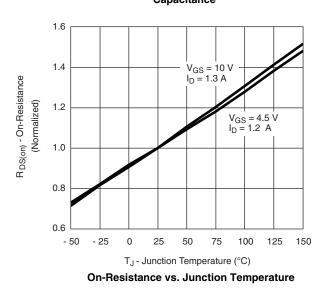
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)







Capacitance

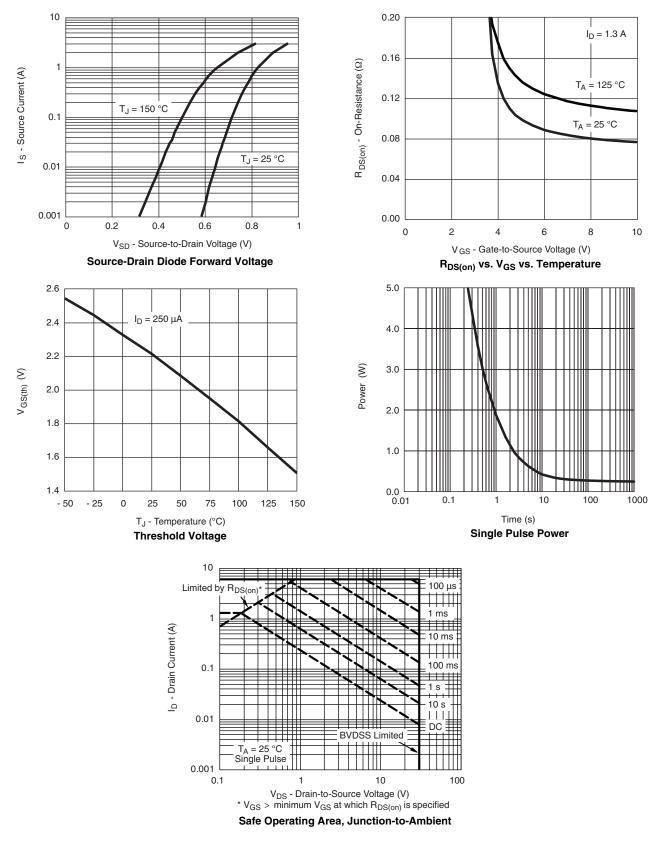


Si1072X

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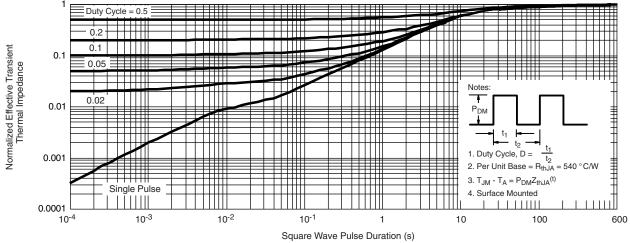


TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





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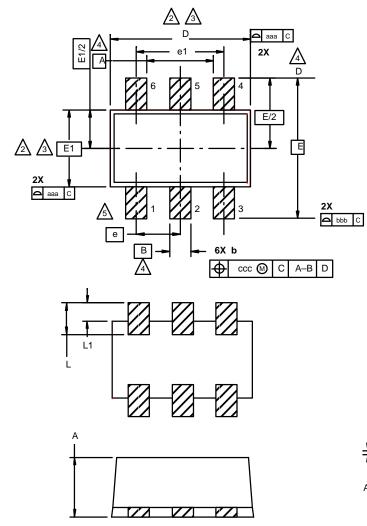


Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?73892.



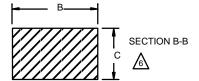
SC89: 6- LEADS (SOT-563F)



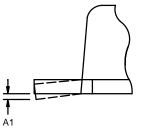
NOTES:

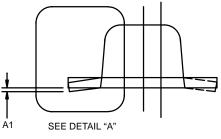
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- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.
- A Datums A, B and D to be determined 0.10 mm from the lead tip.
 - Terminal numbers are shown for reference only.
 - These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









	MILLIMETERS				Tolerances Of Form And	
Dim	Min	Max	Note	Symbol	Position	
Α	0.56	0.60		aaa	0.10	
A1	0.00	0.10		bbb	0.10	
b	0.15	0.30		CCC	0.10	
С	0.10	0.18				
D	1.50	1.70	2, 3			
E	1.55	1.70				
E1	1.20 BSC		2, 3			
е	0.50 BSC					
e1	1.00 BSC					
L	0.35 BSC					
L1	0.20 BSC					
ECN: E-00499—Rev. B, 02-Jul-01 DWG: 5880						



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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